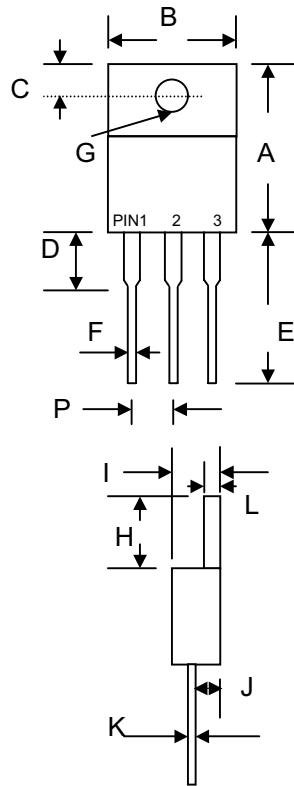


Features

- Glass Passivated Die Construction
- Super-Fast Switching for High Efficiency
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- Green Products in Compliance with the RoHS Directive

Mechanical Data

- Case: ITO-220 Full Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 2.24 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



ITO-220				
Dim	Min	Max	Min	Max
A	14.9	15.1	0.587	0.594
B	—	10.5	—	0.413
C	2.62	2.87	0.103	0.113
D	3.56	4.06	0.140	0.160
E	13.46	14.22	0.530	0.560
F	0.68	0.94	0.027	0.037
G	3.74 Ø	3.91 Ø	0.147 Ø	0.154 Ø
H	5.84	6.86	0.230	0.270
I	4.44	4.70	0.175	0.185
J	2.54	2.79	0.10	0.110
K	0.35	0.64	0.014	0.025
L	1.14	1.40	0.045	0.055
P	2.41	2.67	0.095	0.105
	In mm		In inch	

Maximum Ratings and Electrical Characteristics @_{T_A}=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	FEPF 16AT-G	FEPF 16BT-G	FEPF 16CT-G	FEPF 16DT-G	FEPF 16FT-G	FEPF 16GT-G	FEPF 16JT-G	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	50	100	150	200	300	400	600	V
Working Peak Reverse Voltage	V _{VRM}								
DC Blocking Voltage	V _R								
RMS Reverse Voltage	V _{R(RMS)}	35	70	105	140	210	280	420	V
Average Rectified Output Current @ _{T_C} = 105°C	I _O	16							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	125							A
Forward Voltage @ _{I_F} = 8.0A	V _{FM}	0.95			1.3		1.7		V
Peak Reverse Current @ _{T_A} = 25°C At Rated DC Blocking Voltage @ _{T_A} = 100°C	I _{RM}	10 500							µA
Reverse Recovery Time (Note 1)	t _{rr}	35			50				nS
Typical Junction Capacitance (Note 2)	C _j	80			60				pF
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150							°C

Note: 1. Measured with I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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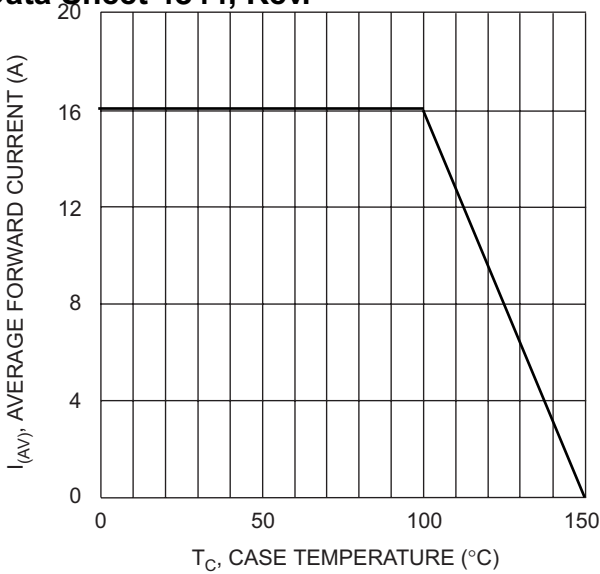


Fig. 1 Forward Current Derating Curve

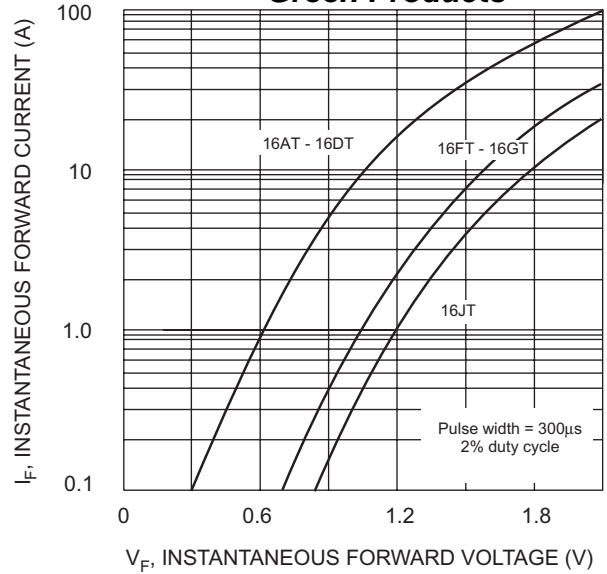


Fig. 2 Typical Forward Characteristics

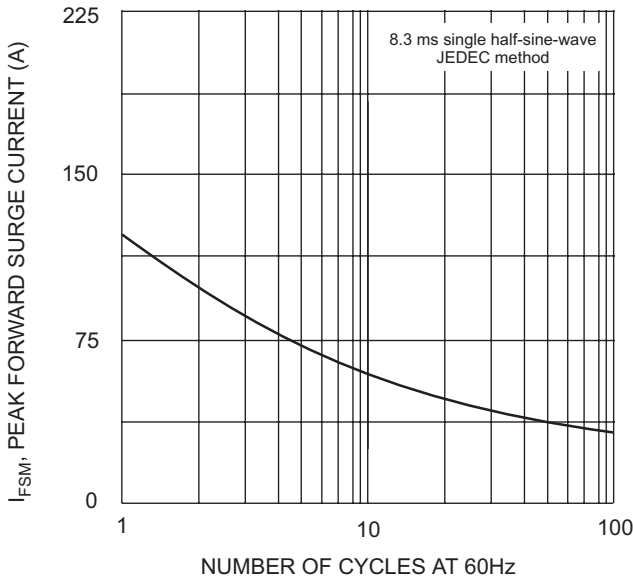


Fig. 3 Maximum Non-Repetitive Surge Current

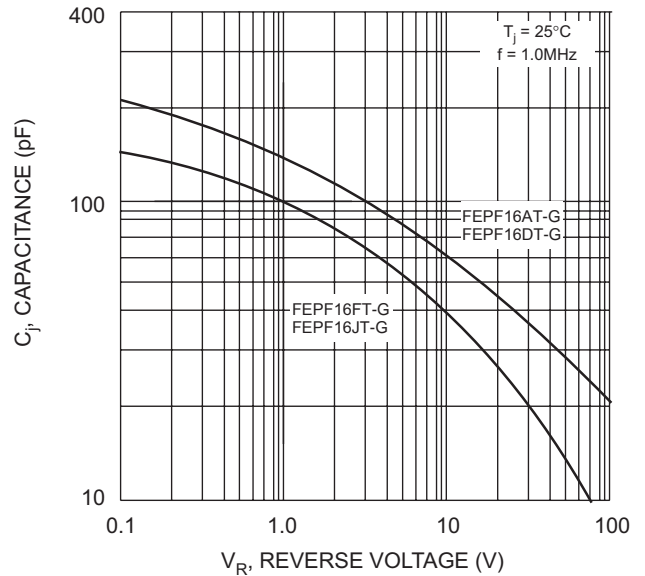
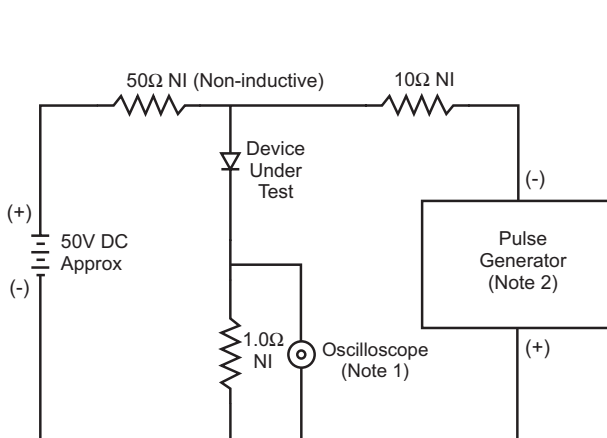
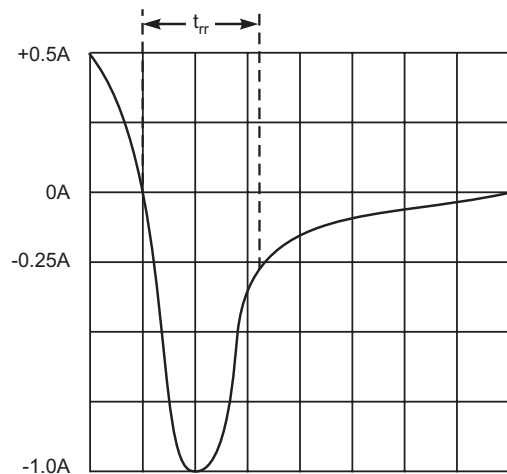


Fig. 4 Typical Junction Capacitance



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

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